

High Voltage, Single and Dual Supply SPDT Analog Switch with Enable Pin

DESCRIPTION

The DG469, DG470 are high voltage SPDT switches, with a typical on resistance of $3.6\ \Omega$ and typical flatness of $0.4\ \Omega$. The DG469, DG470 are identical, except the DG470 provides an enable input. When the enable input is activated, both sides of the switch are in a high impedance mode (Off), maintaining a "Safe State" at power up. This function can also be used as a quick "disconnect" in the event of a fault condition. For audio switching, the enable pin provides a mute function. These are high voltage switches that are fully specified with dual supplies at $\pm 4.5\ \text{V}$ and $\pm 15\ \text{V}$ and a single supply of $12\ \text{V}$ over an operating temperature range from $-40\ ^\circ\text{C}$ to $+125\ ^\circ\text{C}$. Fast switching speeds coupled with high signal bandwidth makes these parts suitable for video switching applications. All digital inputs have $0.8\ \text{V}$ and $2.4\ \text{V}$ logic thresholds ensuring low voltage TTL/CMOS compatibility. Each switch conducts equally well in both directions when on and can handle an input signal range that extends to the supply voltage rails. They exhibit break-before-make switching action to prevent momentary shorting when switching between channels. The DG469, DG470 are offered in a MSOP 8 and SOIC 8 package.

FEATURES

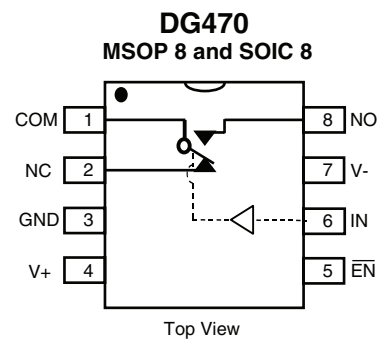
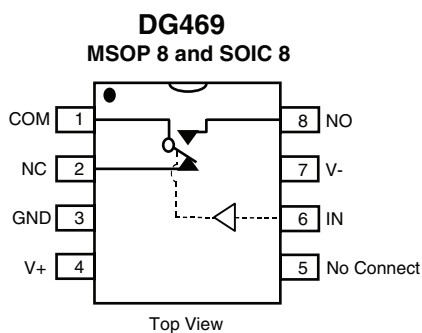
- Low on resistance ($3.6\ \Omega$ typical)
- On resistance flatness ($0.4\ \Omega$ typical)
- $44\ \text{V}$ supply maximum rating
- $\pm 15\ \text{V}$ analog signal range
- Fully specified at supply voltages of $\pm 4.5\ \text{V}$, $12\ \text{V}$ and $\pm 15\ \text{V}$
- TTL/CMOS compatible
- Break before make switching guaranteed
- Total harmonic distortion $0.0145\ \%$
- Compliant to RoHS Directive 2002/95/EC


RoHS
COMPLIANT

APPLICATIONS

- Audio and video signal switching
- Precision automatic test equipment
- Precision data acquisition
- Relay replacement
- Communications systems
- Automotive applications
- Sample and hold systems
- Power routing applications
- Telecom signal switching
- Medical equipment
- Portable and battery power systems

FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION


TRUTH TABLE DG469

Logic	NC	NO
0	ON	OFF
1	OFF	ON

TRUTH TABLE DG470

ENABLE	Logic	NC	NO
0	0	ON	OFF
0	1	OFF	ON
1	X	OFF	OFF

ORDERING INFORMATION		
Temp. Range	Package	Part Number
DG469, DG470		
- 40 °C to 125 °C ^a	8-Pin MSOP	DG469EQ-T1-E3 DG470EQ-T1-E3
	8-Pin Narrow SOIC	DG469EY-T1-E3 DG470EY-T1-E3

Notes:

a. - 40 °C to 85 °C datasheet limits apply.

ABSOLUTE MAXIMUM RATINGS $T_A = 25\text{ °C}$, unless otherwise noted		
Parameter	Limit	Unit
V+ to V-	44	V
GND to V-	25	
Digital Inputs ^a , V_S , V_D	(V-) - 2 to (V+) + 2 or 30 mA, whichever occurs first	
Continuous Current (NO, NC, or COM)	120	mA
Current (Any terminal except NO, NC, or COM)	30	
Peak Current, (Pulsed 1 ms, 10 % Duty Cycle)	200	
Storage Temperature	- 65 to 150	°C
Power Dissipation (Package) ^b	8-Pin MSOP ^c	320
	8-Pin Narrow SOIC ^d	400

Notes:

a. Signals on S_X , D_X , or IN_X exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.

b. All leads welded or soldered to PC board.

c. Derate 4.0 mW/°C above 70 °C.

d. Derate 5.0 mW/°C above 70 °C.

SPECIFICATIONS for Dual Supplies									
Parameter	Symbol	Test Conditions Unless Specified V ₊ = 15 V, V ₋ = - 15 V V _{IN} = 2.4 V, 0.8 V ^a	Temp. ^b	Typ. ^c	- 40 °C to 125 °C		- 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		- 15	15	- 15	15	V
On-Resistance	R _{ON}	I _S = 50 mA, V _D = - 10 V to + 10 V	Room Full	3.6		6 8		6 7	Ω
On-Resistance Match	ΔR _{ON}	I _S = 50 mA, V _D = ± 10 V	Room Full	0.12		0.4 0.9		0.4 0.5	
On-Resistance Flatness	R _{FLATNESS}	I _S = 50 mA, V _D = - 5 V, 0 V, + 5 V	Room Full	0.4		0.5 0.9		0.5 0.8	
Switch Off Leakage Current	I _{S(off)}	V _D = ± 14 V, V _S = ± 14 V	Room Full	± 0.1	- 0.5 - 20	0.5 20	- 0.5 - 2.5	0.5 2.5	nA
	I _{D(off)}		Room Full	± 0.1	- 0.5 - 20	0.5 20	- 0.5 - 2.5	0.5 2.5	
Channel On Leakage Current	I _{D(on)}	V _S = V _D = ± 14 V	Room Full	± 0.2	- 0.5 - 20	0.5 20	- 0.5 - 5	0.5 5	
Digital Control									
Input Current, V _{IN} Low	I _{IL}	V _{IN} Under Test = 0.8 V	Full	0.05	- 1	1	- 1	1	μA
Input Current, V _{IN} High	I _{IH}	V _{IN} Under Test = 2.4 V	Full	0.05	- 1	1	- 1	1	
Input Capacitance ^e	C _{IN}	f = 1 MHz	Room	3.7					pF

SPECIFICATIONS for Dual Supplies									
Parameter	Symbol	Test Conditions Unless Specified V+ = 15 V, V- = - 15 V VIN = 2.4 V, 0.8 V ^a	Temp. ^b	Typ. ^c	- 40 °C to 125 °C		- 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _S = ± 10 V	Room Full	129		166 200		166 185	ns
Turn-Off Time	t _{OFF}		Room Full	80		108 135		108 120	
Break-Before-Make Time Delay	t _D	V _S = 10 V R _L = 300 Ω, C _L = 35 pF	Room	15					
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Room	58					pC
Off Isolation ^e	OIRR	R _L = 50 Ω, C _L = 5 pF f = 1 MHz	Room	- 57					dB
Channel-to-Channel Crosstalk ^e	X _{TALK}		Room	- 63					
Source Off Capacitance ^e	C _{S(off)}	f = 1 MHz	Room	37					pF
Drain Off Capacitance ^e	C _{D(off)}		Room	85					
Channel On Capacitance ^e	C _{D(on)}		Room	125					
Power Supplies									
Power Supply Current	I+	V+ = 16.5 V, V- = - 16.5 V VIN = 0 or 5 V	Room Full	3.0		6 7		6 7	μA
Negative Supply Current	I-		Room Full	- 0.4	- 0.5 - 4.5		- 0.5 - 4.5		
Ground Current	I _{GND}		Room Full	- 3.0	- 6 - 7		- 6 - 7		

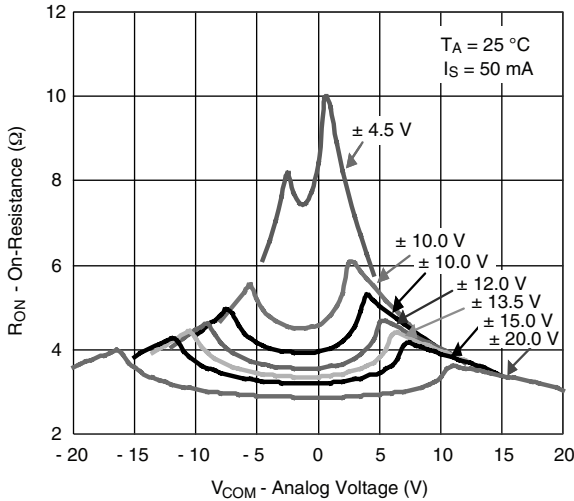
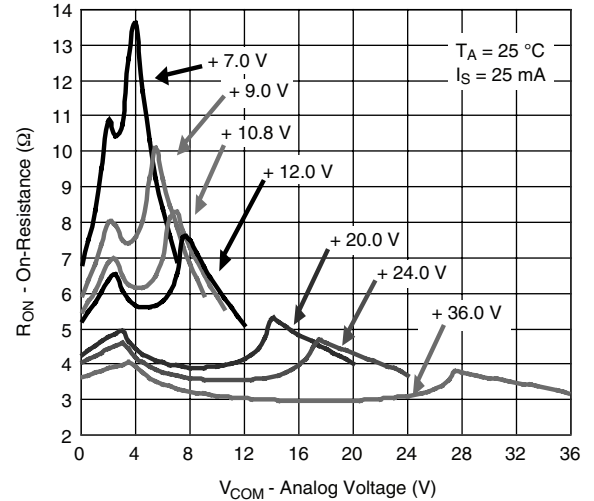
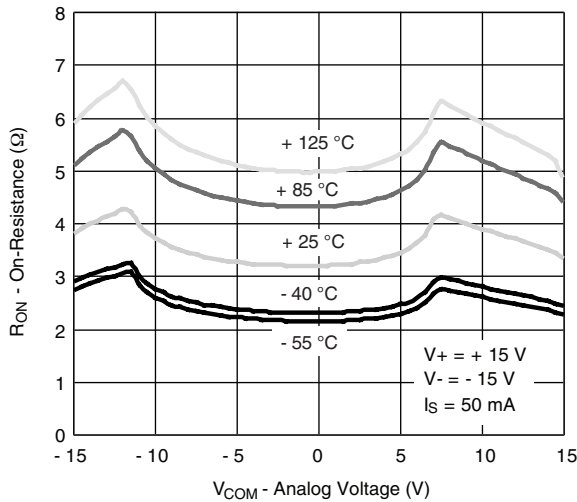
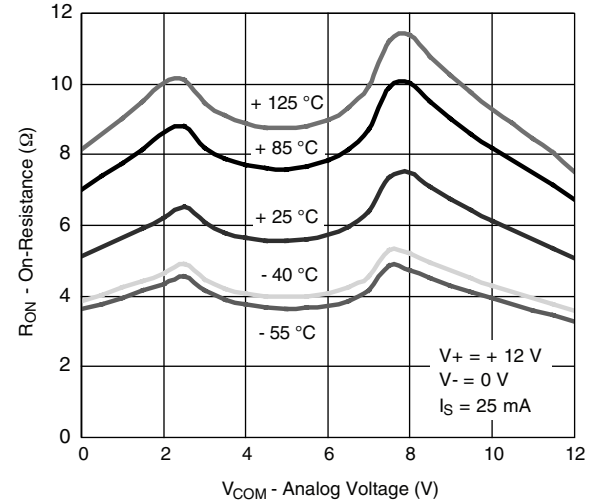
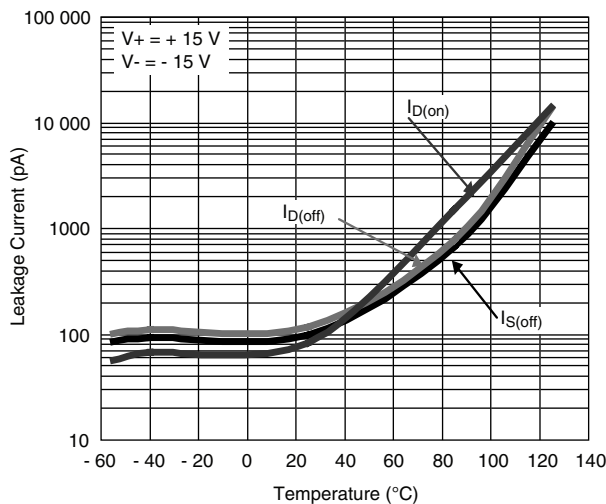
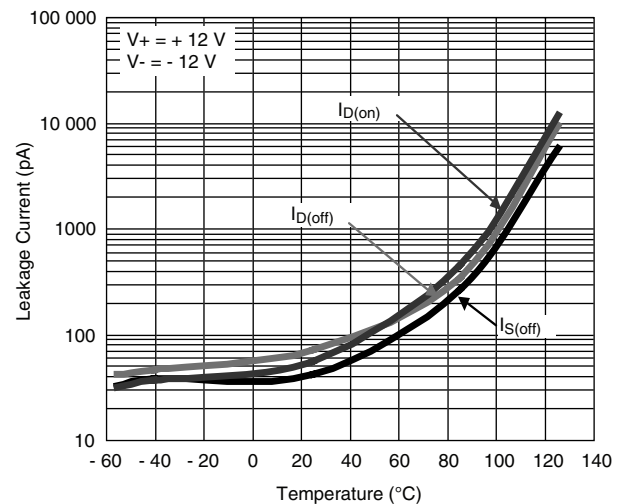
SPECIFICATIONS for Dual Supplies									
Parameter	Symbol	Test Conditions Unless Specified V+ = 4.5 V, V- = - 4.5 V VIN = 2.4 V, 0.8 V ^a	Temp. ^b	Typ. ^c	- 45 °C to 125 °C		- 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full		- 4.5	4.5	- 4.5	4.5	V
On-Resistance ^e	R _{ON}	I _S = 50 mA, V _D = - 2 V to + 2 V	Room Full	8		11 16		11 15	Ω
On-Resistance Match ^e	ΔR _{ON}	I _S = 50 mA, V _D = ± 2 V	Room Full	0.6		0.7 0.9		0.7 0.8	
Dynamic Characteristics									
Turn-On Time ^e	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _S = 2 V	Room Full	245		265 340		65 310	ns
Turn-Off Time ^e	t _{OFF}		Room Full	145		163 200		163 185	
Break-Before-Make ^e Time Delay	t _D	V _S = 2 V R _L = 300 Ω, C _L = 35 pF	Room Full	15					
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Full	58					pC
Power Supplies									
Power Supply Current ^e	I+	VIN = 0 or 4.5 V	Room Full	3.0		6 7		6 7	μA
Negative Supply Current ^e	I-		Room Full	- 0.4	- 0.5 - 4.5		- 0.5 - 4.5		
Ground Current ^e	I _{GND}		Room Full	3.0	- 6 - 7		- 6 - 7		

SPECIFICATIONS for Unipolar Supplies									
Parameter	Symbol	Test Conditions Unless Specified V ₊ = 12 V, V ₋ = 0 V V _{IN} = 2.4 V, 0.8 V ^a	Temp. ^b	Typ. ^c	- 40 °C to 125 °C		- 40 °C to 85 °C		Unit
					Min. ^d	Max. ^d	Min. ^d	Max. ^d	
Analog Switch									
Analog Signal Range ^e	V _{ANALOG}		Full			12		12	V
On-Resistance	R _{ON}	I _S = 25 mA, V _D = 0 V to + 10 V	Room Full	7.5		8.5 14		8.5 11.3	Ω
On-Resistance Match	ΔR _{ON}	I _S = 25 mA, V _D = + 10 V	Room Full	0.4		0.45 0.9		0.45 0.5	
On-Resistance Flatness	R _{FLATNESS}	I _S = 25 mA, V _D = 0 V, + 5 V, + 10 V	Room Full	2.5		2.6 2.9		2.6 2.8	
Dynamic Characteristics									
Turn-On Time	t _{ON}	R _L = 300 Ω, C _L = 35 pF V _S = 10 V	Room Full	190		200 255		200 240	ns
Turn-Off Time	t _{OFF}		Room Full	100		110 135		110 120	
Break-Before-Make Time Delay	t _D	V _S = 10 V R _L = 300 Ω, C _L = 35 pF	Room	50					
Charge Injection ^e	Q	V _g = 0 V, R _g = 0 Ω, C _L = 1 nF	Room	2.4					pC
Power Supplies									
Power Supply Current	I ₊	V _{IN} = 0 or 5 V	Room Full	3.0		6 7		6 7	μA
Negative Supply Current	I ₋		Room Full	- 0.4	- 0.5 - 4.5		- 0.5 - 4.5		
Ground Current	I _{GND}		Room Full	- 3.0	- 6 - 7		- 6 - 7		

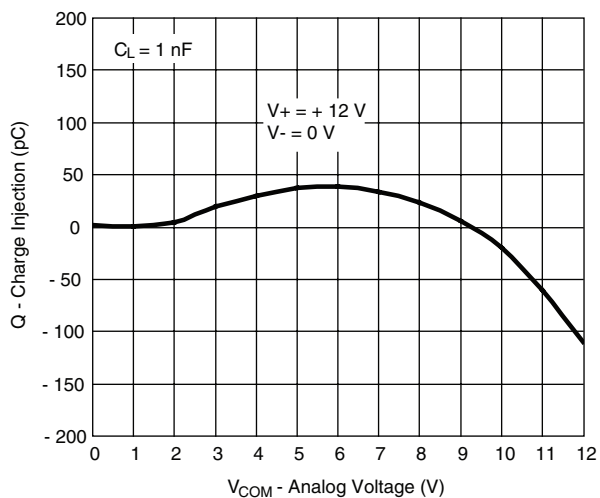
Notes:

- V_{IN} = input voltage to perform proper function.
- Room = 25 °C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- Guaranteed by design, not subject to production test.

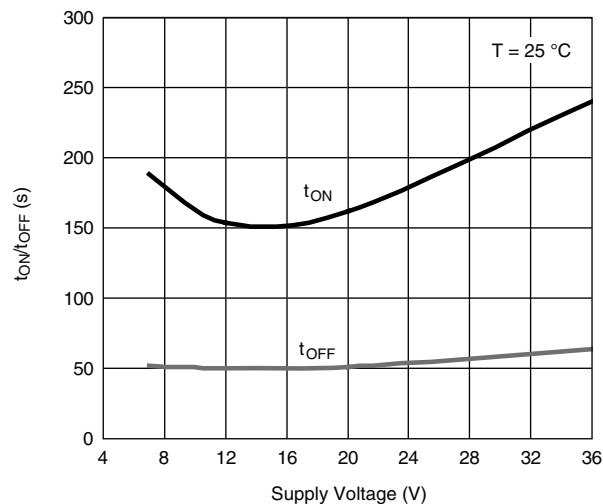
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS

On-Resistance vs. V_D and Dual Supply Voltage

On-Resistance vs. V_D and Single Supply Voltage

On-Resistance vs. V_D and Temperature

On-Resistance vs. V_D and Temperature

Leakage Current vs. Temperature

Leakage Current vs. Temperature

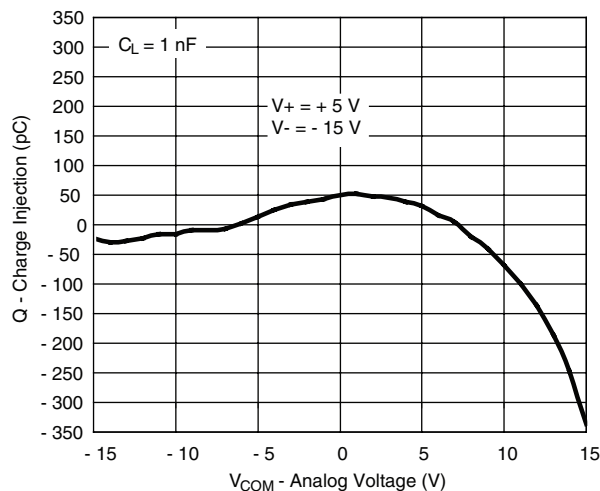
TYPICAL CHARACTERISTICS



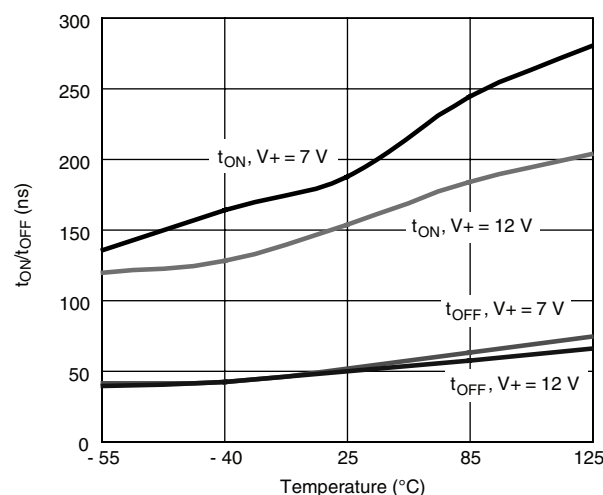
Charge Injection vs. Analog Voltage



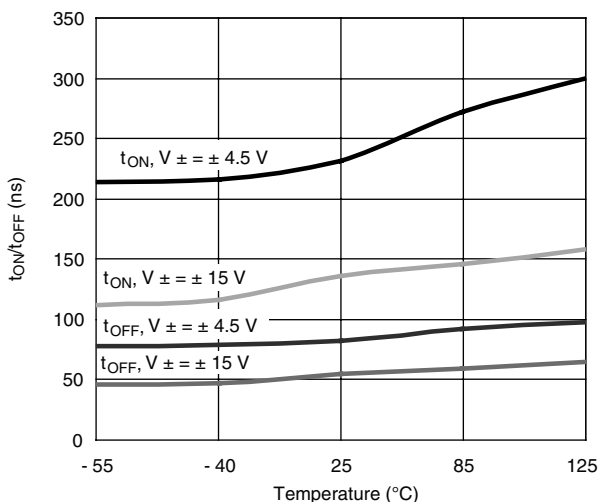
Switching Time vs. Single Supply Voltage



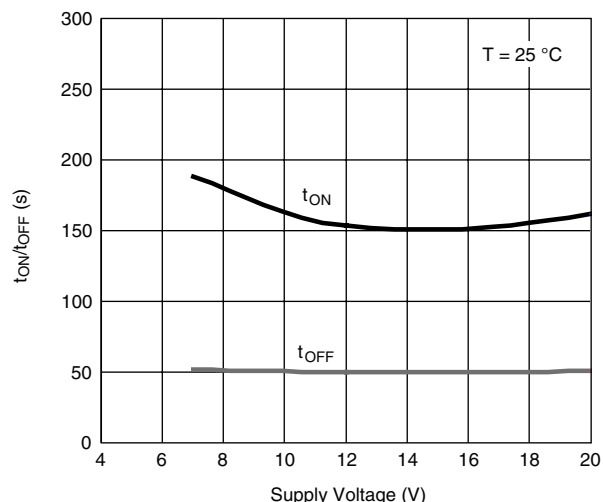
Charge Injection vs. Analog Voltage



Switching Time vs. Temperature and Single Supply Voltage

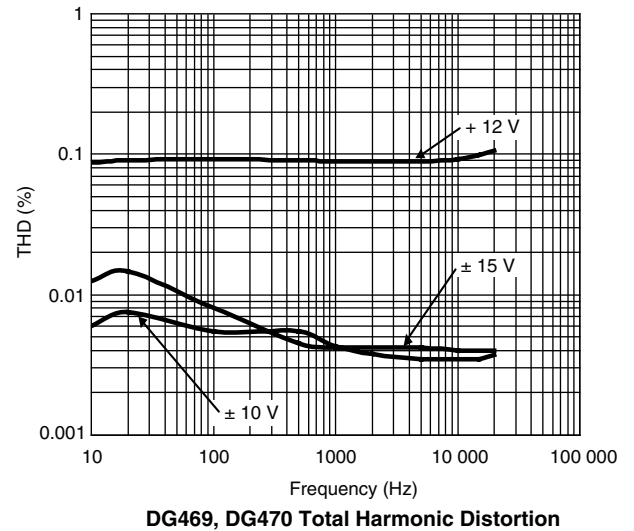
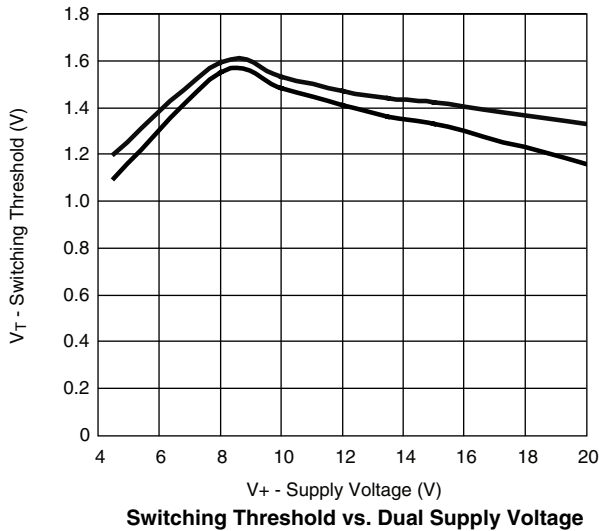
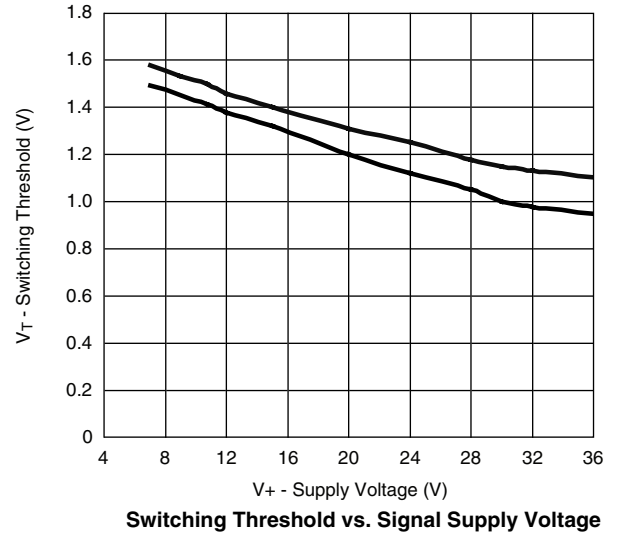
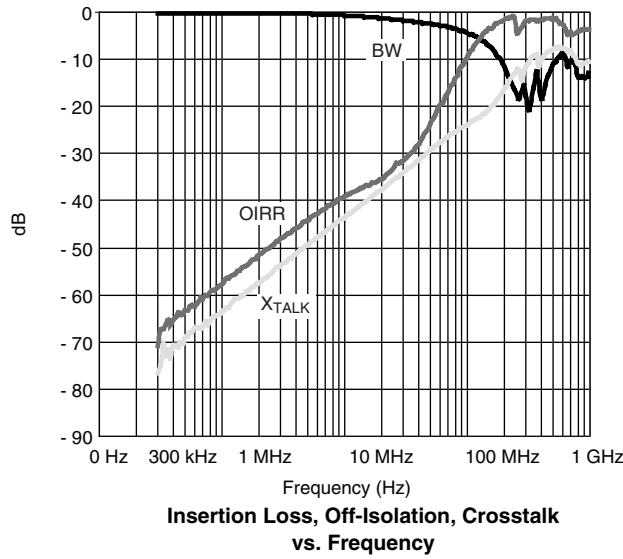


Switching Time vs. Temperature and Dual Supply Voltage

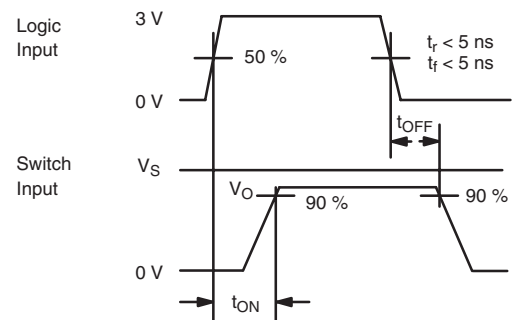
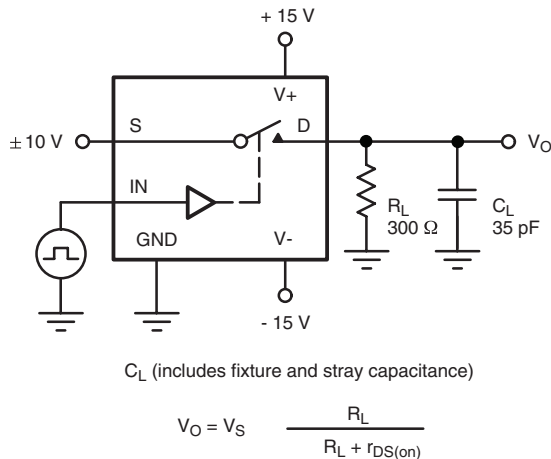


Switching Time vs. Dual Supply Voltage

TYPICAL CHARACTERISTICS



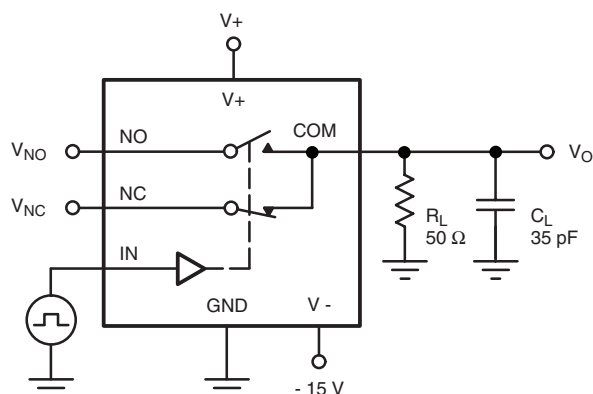
TEST CIRCUITS



Note: Logic input waveform is inverted for switches that have the opposite logic sense control.

Figure 1. Switching Time

TEST CIRCUITS



C_L (includes fixture and stray capacitance)

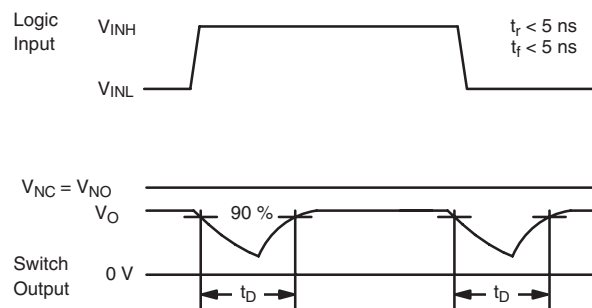


Figure 2. Break-Before-Make

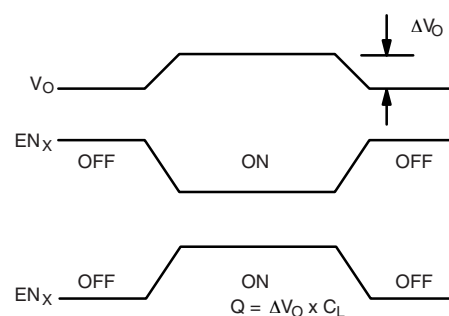
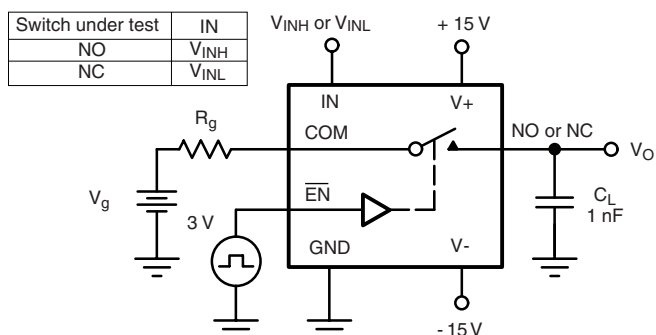


Figure 3. Charge Injection

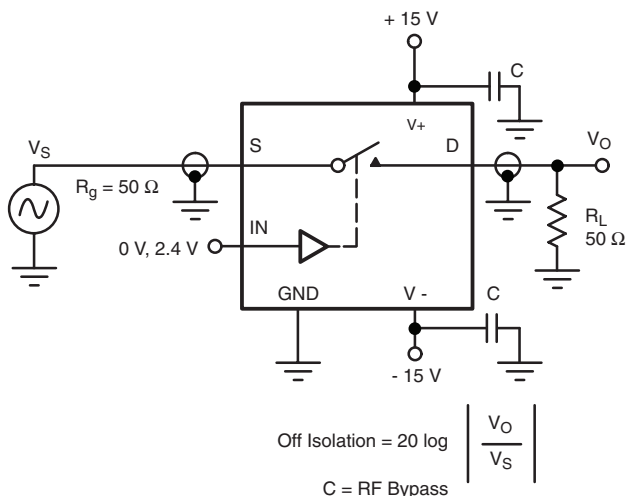


Figure 4. Off-Isolation

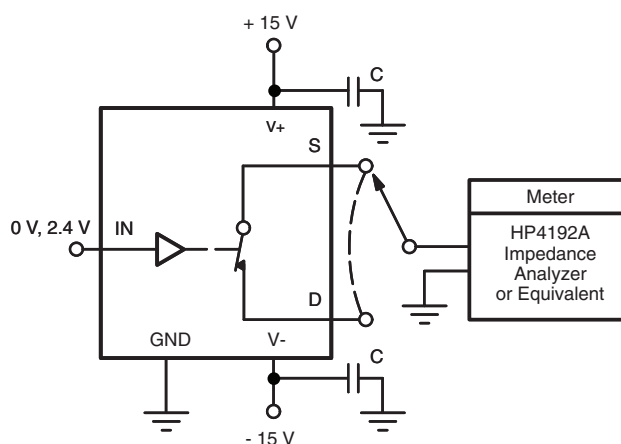


Figure 5. Source/Drain Capacitances

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Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9